www.ti.com

Dual Precision, 17 MHz, Low Noise, CMOS Input Amplifier

Check for Samples: SM73307

FEATURES

- Unless Otherwise Noted, Typical Values at V_S = 5V.
- Renewable Energy Grade
- Input Offset Voltage ±150 µV (max)
- **Input Bias Current 100 fA**
- Input Voltage Noise 5.8 nV/√Hz
- **Gain Bandwidth Product 17 MHz**
- Supply Current 1.30 mA
- Supply Voltage Range 1.8V to 5.5V
- THD+N @ f = 1 kHz 0.001%
- Operating Temperature Range -40°C to 125°C
- Rail-to-rail Output Swing
- 8-Pin VSSOP Package

APPLICATIONS

- **Photovoltaic Electronics**
- **Active Filters and Buffers**
- **Sensor Interface Applications**
- **Transimpedance Amplifiers**
- **Automotive**

DESCRIPTION

The SM73307 is a dual, low noise, low offset, CMOS input, rail-to-rail output precision amplifier with a high gain bandwidth product. The SM73307 is ideal for a variety of instrumentation applications including solar photovoltaic.

Utilizing a CMOS input stage, the SM73307 achieves an input bias current of 100 fA, an input referred voltage noise of 5.8 nV/√Hz, and an input offset voltage of less than ±150 µV. These features make the SM73307 a superior choice for precision applications.

Consuming only 1.30 mA of supply current per channel, the SM73307 offers a high gain bandwidth product of 17 MHz, enabling accurate amplification at high closed loop gains.

The SM73307 has a supply voltage range of 1.8V to 5.5V, which makes it an ideal choice for portable low power applications with low supply voltage requirements.

The SM73307 is built with TI's advanced VIP50 process technology and is offered in an 8-pin VSSOP package.

The SM73307 incorporates enhanced manufacturing and support processes for the photovoltaic and automotive market, including defect detection methodologies. Reliability qualification is compliant with the requirements and temperature grades defined in the Renewable Energy Grade and AEC-Q100 standards.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings (1)(2)

Abbolato maximam Rating	<u> </u>	
ESD Tolerance ⁽³⁾	Human Body Model	2000V
	Machine Model	200V
	Charge-Device Model	1000V
V _{IN} Differential		±0.3V
Supply Voltage $(V_S = V^+ - V^-)$		6.0V
Voltage on Input/Output Pins		V ⁺ +0.3V, V [−] −0.3V
Storage Temperature Range		−65°C to 150°C
Junction Temperature ⁽⁴⁾		+150°C
Soldering Information	Infrared or Convection (20 sec)	235°C
	Wave Soldering Lead Temp. (10 sec)	260°C

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional. For specifications and the test conditions, see the Electrical Characteristics Tables.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) Human Body Model, applicable std. MIL-STD-883, Method 3015.7. Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC)Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).
- (4) The maximum power dissipation is a function of T_{J(MAX)}, θ_{JA}. The maximum allowable power dissipation at any ambient temperature is P_D = (T_{J(MAX)} - T_A)/θ_{JA}. All numbers apply for packages soldered directly onto a PC Board.

Operating Ratings⁽¹⁾

Temperature Range ⁽²⁾		-40°C to 125°C
Supply Voltage $(V_S = V^+ - V^-)$	0°C ≤ T _A ≤ 125°C	1.8V to 5.5V
	-40°C ≤ T _A ≤ 125°C	2.0V to 5.5V
Package Thermal Resistance (θ _{JA} ⁽²⁾)	8-Pin VSSOP	236°C/W

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional. For specifications and the test conditions, see the Electrical Characteristics Tables.
- (2) The maximum power dissipation is a function of $T_{J(MAX)}$, θ_{JA} . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} T_A)/\theta_{JA}$. All numbers apply for packages soldered directly onto a PC Board.

2.5V Electrical Characteristics

Unless otherwise specified, all limits are specified for $T_A = 25^{\circ}C$, $V^+ = 2.5V$, $V^- = 0V$, $V_O = V_{CM} = V^+/2$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Co	Min ⁽¹⁾	Typ ⁽²⁾	Max ⁽¹⁾	Units	
V	Input Offset Voltage	-20°C ≤ T _A ≤ 85°C			±20	±180 ±330	\/
Vos	Input Offset Voltage	-40°C ≤ T _A ≤ 125°		±20	±180 ±430	μV	
TC V _{OS}	Input Offset Voltage Temperature Drift (3)(4)				-1.75	±4	μV/°C
	Input Rice Current	$V_{CM} = 1.0V^{(5)(4)}$	-40°C ≤ T _A ≤ 85°C		0.05	1 25	~ ^
IB	Input Bias Current	V _{CM} = 1.0V (7/7)	-40°C ≤ T _A ≤ 125°C		0.05	1 100	рA

- Limits are 100% production tested at 25°C. Limits over the operating temperature range are specified through correlations using the Statistical Quality Control (SQC) method.
- (2) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.
- (3) Offset voltage average drift is determined by dividing the change in V_{OS} at the temperature extremes by the total temperature change.
- 4) This parameter is specified by design and/or characterization and is not tested in production.
- (5) Positive current corresponds to current flowing into the device.



2.5V Electrical Characteristics (continued)

Unless otherwise specified, all limits are specified for $T_A = 25^{\circ}C$, $V^+ = 2.5V$, $V^- = 0V$, $V_O = V_{CM} = V^+/2$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min ⁽¹⁾	Typ ⁽²⁾	Max ⁽¹⁾	Units
I _{OS}	Input Offset Current	$V_{CM} = 1V^{(4)}$		0.006	0.5 50	рА
CMRR	Common Mode Rejection Ratio	0V ≤ V _{CM} ≤ 1.4V	83 80	100		dB
DODD	David Outside Date of the Date	$2.0V \le V^+ \le 5.5V$ $V^- = 0V, V_{CM} = 0$	85 80	100		-ID
PSRR	Power Supply Rejection Ratio	$1.8V \le V^+ \le 5.5V$ $V^- = 0V, V_{CM} = 0$	85	98		dB
CMVR	Common Mode Voltage Range	CMRR ≥ 80 dB CMRR ≥ 78 dB	-0.3 - 0.3		1.5 1.5	V
•	Once I are Veltage On's	$V_{O} = 0.15 \text{ to } 2.2V$ $R_{L} = 2 \text{ k}\Omega \text{ to } V^{+}/2$	84 80	92		-ID
A _{VOL}	Open Loop Voltage Gain	$V_{O} = 0.15 \text{ to } 2.2V$ $R_{L} = 10 \text{ k}\Omega \text{ to } V^{+}/2$	90 86	95		dB
	Output Voltage Swing	$R_L = 2 k\Omega \text{ to } V^+/2$		25	70 77	
	High	$R_L = 10 \text{ k}\Omega \text{ to V}^+/2$		20	60 66	mV from
V _{OUT}	Output Voltage Swing Low	$R_L = 2 k\Omega \text{ to } V^+/2$		30	70 73	either rail
		$R_L = 10 \text{ k}\Omega \text{ to V}^+/2$		15	60 62	
		Sourcing to V ⁻ V _{IN} = 200 mV ⁽⁶⁾	36 30	52		
I _{OUT}	Output Current	Sinking to V ⁺ $V_{IN} = -200 \text{ mV}^{(6)}$	7.5 5.0	15		mA mA
I _S	Supply Current	Per Channel		1.10	1.50 1.85	mA
SR	Slew Rate	$A_V = +1$, Rising (10% to 90%)		8.3		\//uo
SK	Siew Rate	$A_V = +1$, Falling (90% to 10%)		10.3		V/µs
GBW	Gain Bandwidth			14		MHz
_	Input Referred Voltage Noise Density	f = 400 Hz		6.8		nV/√ Hz
e _n	Input Referred Voltage Noise Density	f = 1 kHz 5.8				IIV/ VIIZ
i _n	Input Referred Current Noise Density	f = 1 kHz		0.01		pA/√Hz
TUD.N	Tatal Harmania Diatantian . Naisa	$f = 1 \text{ kHz}, A_V = 1, R_L = 100 \text{ k}\Omega$ $V_O = 0.9 \text{ V}_{PP}$		0.003		0/
THD+N	Total Harmonic Distortion + Noise	$f = 1 \text{ kHz}, A_V = 1, R_L = 600\Omega$ $V_O = 0.9 \text{ V}_{PP}$		0.004		%

⁽⁶⁾ The short circuit test is a momentary open loop test.



5V Electrical Characteristics

Unless otherwise specified, all limits are specified for $T_A = 25^{\circ}C$, $V^+ = 5V$, $V^- = 0V$, $V_{CM} = V^+/2$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions		Min ⁽¹⁾	Typ ⁽²⁾	Max ⁽¹⁾	Units
V	Input Offset Voltage	-20°C ≤ T _A ≤ 85°C	C		±10	±150 ±300	μV
V _{OS}	Input Onset Voltage	-40°C ≤ T _A ≤ 125°	°C		±10	±150 ±400	μν
TC V _{OS}	Input Offset Voltage Temperature Drift (3) (4)				-1.75	±4	μV/°C
	Input Ding Current	$V_{CM} = 2.0V^{(5)(4)}$	-40°C ≤ T _A ≤ 85°C		0.1	1 25	20
l _B	Input Bias Current	V _{CM} = 2.0 V (5)(3)	-40°C ≤ T _A ≤ 125°C		0.1	1 100	рA
I _{OS}	Input Offset Current	$V_{CM} = 2.0V^{(4)}$			0.01	0.5 50	pA
CMRR	Common Mode Rejection Ratio	0V ≤ V _{CM} ≤ 3.7V		85 82	100		dB
DODD	Daniel Daientie Datie	$2.0V \le V^{+} \le 5.5V$ $V^{-} = 0V, V_{CM} = 0$	85 80	100		.ID	
PSRR Power Supply Rejection Ratio		$1.8V \le V^{+} \le 5.5V$ $V^{-} = 0V, V_{CM} = 0$	85	98		dB	
CMVR	Common Mode Voltage Range	CMRR ≥ 80 dB CMRR ≥ 78 dB	-0.3 - 0.3		4 4	V	
		$V_{O} = 0.3 \text{ to } 4.7V$ $R_{L} = 2 \text{ k}\Omega \text{ to } V^{+}/2$		84 80	90		
A _{VOL}	Open Loop Voltage Gain	$V_O = 0.3 \text{ to } 4.7V$ $R_L = 10 \text{ k}\Omega \text{ to } V^+/2$	90 86	95		dB	
	Output Voltage Swing	$R_L = 2 k\Omega \text{ to } V^+/2$			32	70 77	
.,	High	$R_L = 10 \text{ k}\Omega \text{ to V}^+/2$	2		22	60 66	mV from
V _{OUT}	Output Voltage Swing	$R_L = 2 k\Omega \text{ to } V^+/2$			45	75 78	either rail
	Low	$R_L = 10 \text{ k}\Omega \text{ to V}^+/2$		20	60 62		
		Sourcing to V ⁻ V _{IN} = 200 mV ⁽⁶⁾		46 38	66		
I _{OUT}	Output Current	Sinking to V ⁺ $V_{IN} = -200 \text{ mV}^{(6)}$	10.5 6.5	23		mA	
I _S	Supply Current	(per channel)			1.30	1.70 2.05	mA

⁽¹⁾ Limits are 100% production tested at 25°C. Limits over the operating temperature range are specified through correlations using the Statistical Quality Control (SQC) method.

⁽²⁾ Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.

⁽³⁾ Offset voltage average drift is determined by dividing the change in V_{OS} at the temperature extremes by the total temperature change.

⁽⁴⁾ This parameter is specified by design and/or characterization and is not tested in production.

⁽⁵⁾ Positive current corresponds to current flowing into the device.

⁽⁶⁾ The short circuit test is a momentary open loop test.



5V Electrical Characteristics (continued)

Unless otherwise specified, all limits are specified for $T_A = 25^{\circ}C$, $V^+ = 5V$, $V^- = 0V$, $V_{CM} = V^+/2$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min ⁽¹⁾	Typ ⁽²⁾	Max ⁽¹⁾	Units
CD	Claur Rote	$A_V = +1$, Rising (10% to 90%)	6.0	9.5		1////
SR	Slew Rate	$A_V = +1$, Falling (90% to 10%)	7.5	11.5		V/µs
GBW	Gain Bandwidth			17		MHz
	Input Referred Voltage Noise Density	f = 400 Hz		7.0		nV/√ Hz
e _n		f = 1 kHz		5.8		IIV/VIIZ
i _n	Input Referred Current Noise Density	f = 1 kHz		0.01		pA/√ Hz
THD+N	Total Harmonic Distortion + Noise	$f = 1 \text{ kHz}, A_V = 1, R_L = 100 \text{ k}\Omega$ $V_O = 4 \text{ V}_{PP}$		0.001		0/
		f = 1 kHz, A_V = 1, R_L = 600 Ω V_O = 4 V_{PP}		0.004		%

Connection Diagram

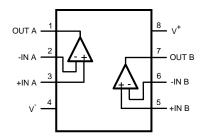


Figure 1. 8-Pin VSSOP – Top View See Package Number DGK



Typical Performance Characteristics

Unless otherwise noted: $T_A = 25$ °C, $V_S = 5$ V, $V_{CM} = V_S/2$.

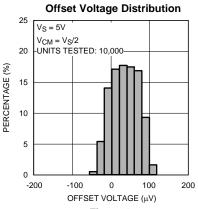


Figure 2.

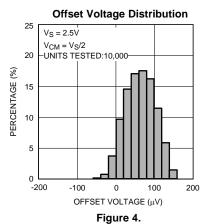
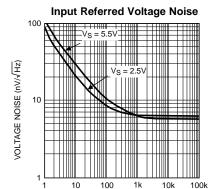
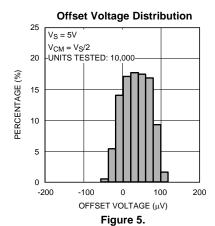


Figure 6.



FREQUENCY (Hz) Figure 3.



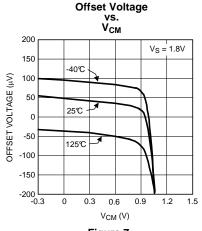


Figure 7.



Unless otherwise noted: $T_A = 25$ °C, $V_S = 5V$, $V_{CM} = V_S/2$.

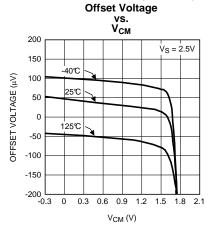


Figure 8.

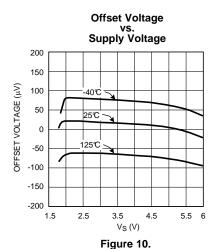


Figure 12.

Input Bias Current

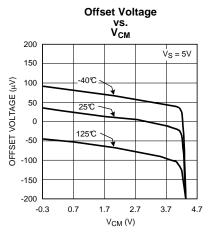


Figure 9.

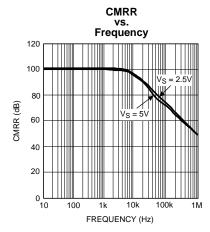
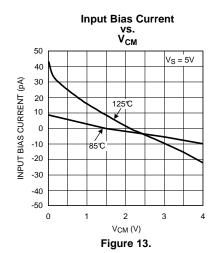


Figure 11.



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Product Folder Links: SM73307



Unless otherwise noted: $T_A = 25$ °C, $V_S = 5V$, $V_{CM} = V_S/2$.

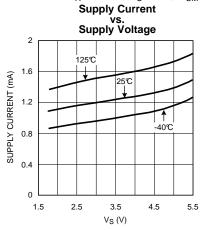


Figure 14.

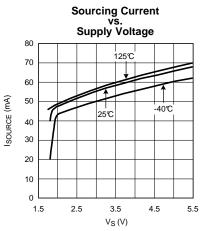
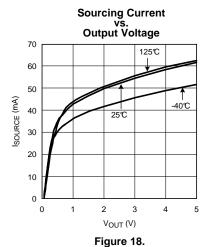


Figure 16.



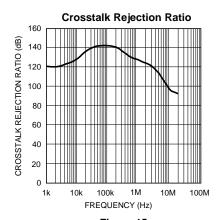


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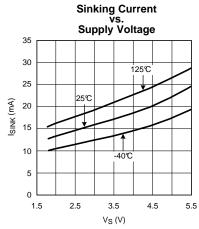


Figure 17.

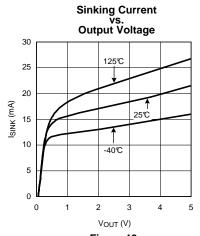
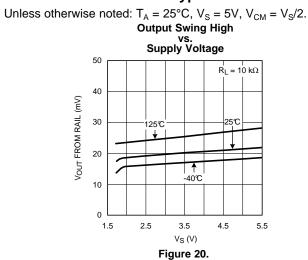
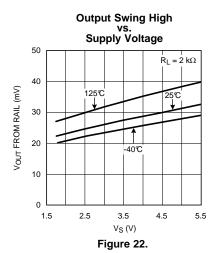
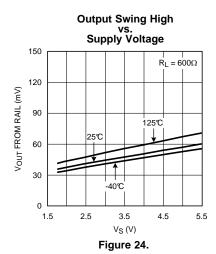


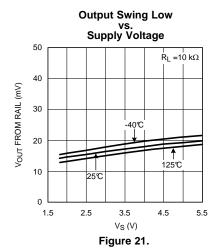
Figure 19.

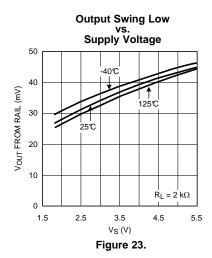


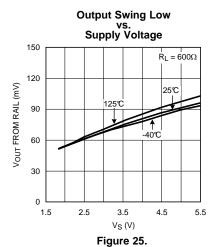














Unless otherwise noted: $T_A = 25$ °C, $V_S = 5$ V, $V_{CM} = V_S/2$.

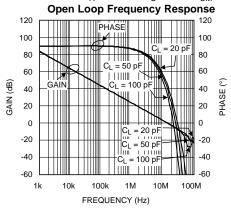
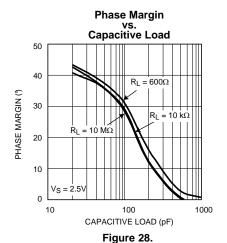


Figure 26.



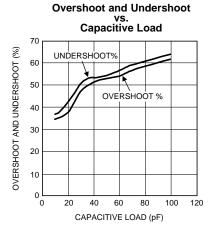


Figure 30.

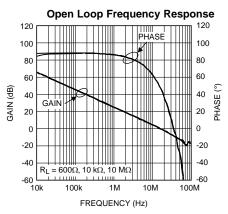
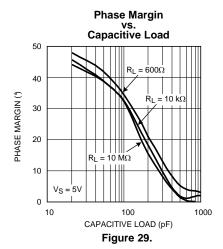


Figure 27.



Slew Rate
VS.
Supply Voltage

12

11

FALLING EDGE

11

11

RISING EDGE

7

1.5

2.5

3.5

4.5

5.5

6

Figure 31.



Unless otherwise noted: $T_A = 25$ °C, $V_S = 5V$, $V_{CM} = V_S/2$.

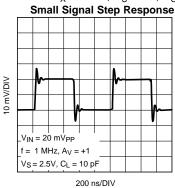


Figure 32.

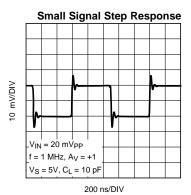
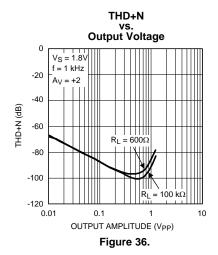


Figure 34.



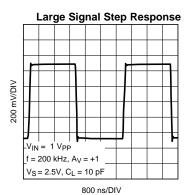


Figure 33.

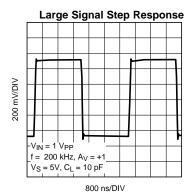
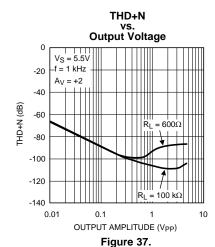
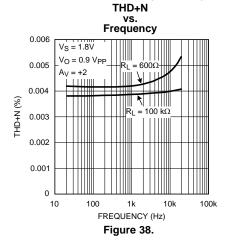


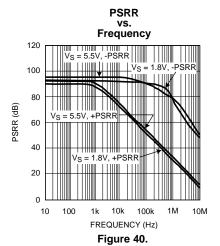
Figure 35.





Unless otherwise noted: $T_A = 25$ °C, $V_S = 5V$, $V_{CM} = V_S/2$.





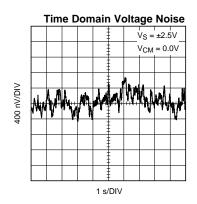
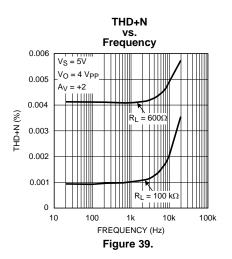


Figure 42.



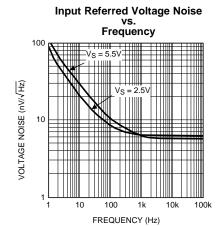
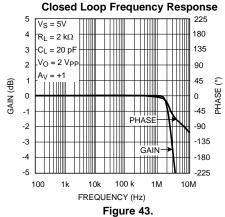


Figure 41.



4.



Unless otherwise noted: $T_A = 25^{\circ}C$, $V_S = 5V$, $V_{CM} = V_S/2$. Closed Loop Output Impedance vs. Frequency OUTPUT IMPEDANCE (Ω)

FREQUENCY (Hz) Figure 44.

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APPLICATION INFORMATION

The SM73307 is a dual, low noise, low offset, rail-to-rail output precision amplifier with a wide gain bandwidth product of 17 MHz and low supply current. The wide bandwidth makes the SM73307 an ideal choice for wideband amplification in photovoltaic and portable applications.

The SM73307 is superior for sensor applications. The very low input referred voltage noise of only 5.8 nV/ $\sqrt{\text{Hz}}$ at 1 kHz and very low input referred current noise of only 10 fA/ $\sqrt{\text{Hz}}$ mean more signal fidelity and higher signal-to-noise ratio.

The SM73307 has a supply voltage range of 1.8V to 5.5V over a wide temperature range of 0° C to 125° C. This is optimal for low voltage commercial applications. For applications where the ambient temperature might be less than 0° C, the SM73307 is fully operational at supply voltages of 2.0V to 5.5V over the temperature range of -40° C to 125° C.

The outputs of the SM73307 swing within 25 mV of either rail providing maximum dynamic range in applications requiring low supply voltage. The input common mode range of the SM73307 extends to 300 mV below ground. This feature enables users to utilize this device in single supply applications.

The use of a very innovative feedback topology has enhanced the current drive capability of the SM73307, resulting in sourcing currents of as much as 47 mA with a supply voltage of only 1.8V.

The SM73307 is offered in an 8-pin VSSOP package. This small package is an ideal solution for applications requiring minimum PC board footprint.

CAPACITIVE LOAD

The unity gain follower is the most sensitive configuration to capacitive loading. The combination of a capacitive load placed directly on the output of an amplifier along with the output impedance of the amplifier creates a phase lag which in turn reduces the phase margin of the amplifier. If phase margin is significantly reduced, the response will be either under-damped or the amplifier will oscillate.

The SM73307 can directly drive capacitive loads of up to 120 pF without oscillating. To drive heavier capacitive loads, an isolation resistor, $R_{\rm ISO}$ as shown in Figure 45, should be used. This resistor and $C_{\rm L}$ form a pole and hence delay the phase lag or increase the phase margin of the overall system. The larger the value of $R_{\rm ISO}$, the more stable the output voltage will be. However, larger values of $R_{\rm ISO}$ result in reduced output swing and reduced output current drive.

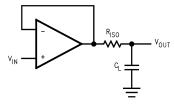


Figure 45. Isolating Capacitive Load

INPUT CAPACITANCE

CMOS input stages inherently have low input bias current and higher input referred voltage noise. The SM73307 enhances this performance by having the low input bias current of only 50 fA, as well as, a very low input referred voltage noise of 5.8 nV/\(\text{Hz}\). In order to achieve this a larger input stage has been used. This larger input stage increases the input capacitance of the SM73307. Figure 46 shows typical input common mode capacitance of the SM73307.



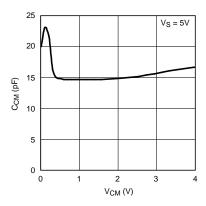


Figure 46. Input Common Mode Capacitance

This input capacitance will interact with other impedances, such as gain and feedback resistors which are seen on the inputs of the amplifier, to form a pole. This pole will have little or no effect on the output of the amplifier at low frequencies and under DC conditions, but will play a bigger role as the frequency increases. At higher frequencies, the presence of this pole will decrease phase margin and also cause gain peaking. In order to compensate for the input capacitance, care must be taken in choosing feedback resistors. In addition to being selective in picking values for the feedback resistor, a capacitor can be added to the feedback path to increase stability.

The DC gain of the circuit shown in Figure 47 is simply $-R_2/R_1$.

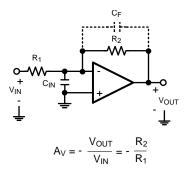


Figure 47. Compensating for Input Capacitance

For the time being, ignore C_F. The AC gain of the circuit in Figure 47 can be calculated as follows:

$$\frac{V_{\text{OUT}}}{V_{\text{IN}}}(s) = \frac{-R_2/R_1}{\left[1 + \frac{s}{\left(\frac{A_0 R_1}{R_1 + R_2}\right)} + \frac{s^2}{\left(\frac{A_0}{C_{\text{IN}} R_2}\right)}\right]}$$
(1)

This equation is rearranged to find the location of the two poles:

$$P_{1,2} = \frac{-1}{2C_{IN}} \left[\frac{1}{R_1} + \frac{1}{R_2} \pm \sqrt{\left(\frac{1}{R_1} + \frac{1}{R_2}\right)^2 - \frac{4 A_0 C_{IN}}{R_2}} \right]$$
 (2)

As shown in Equation 2, as the values of R_1 and R_2 are increased, the magnitude of the poles are reduced, which in turn decreases the bandwidth of the amplifier. Figure 48 shows the frequency response with different value resistors for R_1 and R_2 . Whenever possible, it is best to choose smaller feedback resistors.

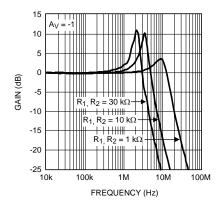


Figure 48. Closed Loop Frequency Response

As mentioned before, adding a capacitor to the feedback path will decrease the peaking. This is because C_F will form yet another pole in the system and will prevent pairs of poles, or complex conjugates from forming. It is the presence of pairs of poles that cause the peaking of gain. Figure 49 shows the frequency response of the schematic presented in Figure 47 with different values of C_F . As can be seen, using a small value capacitor significantly reduces or eliminates the peaking.

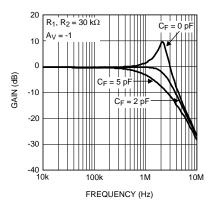


Figure 49. Closed Loop Frequency Response

TRANSIMPEDANCE AMPLIFIER

In many applications the signal of interest is a very small amount of current that needs to be detected. Current that is transmitted through a photodiode is a good example. Barcode scanners, light meters, fiber optic receivers, and industrial sensors are some typical applications utilizing photodiodes for current detection. This current needs to be amplified before it can be further processed. This amplification is performed using a current-to-voltage converter configuration or transimpedance amplifier. The signal of interest is fed to the inverting input of an op amp with a feedback resistor in the current path. The voltage at the output of this amplifier will be equal to the negative of the input current times the value of the feedback resistor. Figure 50 shows a transimpedance amplifier configuration. C_D represents the photodiode parasitic capacitance and C_{CM} denotes the common-mode capacitance of the amplifier. The presence of all of these capacitances at higher frequencies might lead to less stable topologies at higher frequencies. Care must be taken when designing a transimpedance amplifier to prevent the circuit from oscillating.

With a wide gain bandwidth product, low input bias current and low input voltage and current noise, the SM73307 is ideal for wideband transimpedance applications.



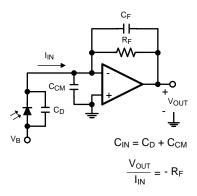


Figure 50. Transimpedance Amplifier

A feedback capacitance C_F is usually added in parallel with R_F to maintain circuit stability and to control the frequency response. To achieve a maximally flat, 2^{nd} order response, R_F and C_F should be chosen by using Equation 3:

$$C_F = \sqrt{\frac{C_{IN}}{GBWP * 2 \pi R_F}}$$
(3)

Calculating C_F from Equation 3 can sometimes result in capacitor values which are less than 2 pF. This is especially the case for high speed applications. In these instances, it is often more practical to use the circuit shown in Figure 51 in order to allow more sensible choices for C_F . The new feedback capacitor, C_F , is (1+ R_B/R_A) C_F . This relationship holds as long as $R_A << R_F$.

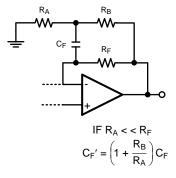


Figure 51. Modified Transimpedance Amplifier

SENSOR INTERFACE

The SM73307 has a low input bias current and low input referred noise, which makes it an ideal choice for sensor interfaces such as thermopiles, Infra Red (IR) thermometry, thermocouple amplifiers, and pH electrode buffers.

Thermopiles generate voltage in response to receiving radiation. These voltages are often only a few microvolts. As a result, the operational amplifier used for this application needs to have low offset voltage, low input voltage noise, and low input bias current. Figure 52 shows a thermopile application where the sensor detects radiation from a distance and generates a voltage that is proportional to the intensity of the radiation. The two resistors, R_A and R_B , are selected to provide high gain to amplify this signal, while C_F removes the high frequency noise.



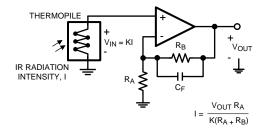


Figure 52. Thermopile Sensor Interface

PRECISION RECTIFIER

Rectifiers are electrical circuits used for converting AC signals to DC signals. Figure 53 shows a full-wave precision rectifier. Each operational amplifier used in this circuit has a diode on its output. This means for the diodes to conduct, the output of the amplifier needs to be positive with respect to ground. If V_{IN} is in its positive half cycle then only the output of the bottom amplifier will be positive. As a result, the diode on the output of the bottom amplifier will conduct and the signal will show at the output of the circuit. If V_{IN} is in its negative half cycle then the output of the top amplifier will be positive, resulting in the diode on the output of the top amplifier conducting and delivering the signal from the amplifier's output to the circuit's output.

For $R_2/R_1 \ge 2$, the resistor values can be found by using the equation shown in Figure 53. If $R_2/R_1 = 1$, then R_3 should be left open, no resistor needed, and R_4 should simply be shorted.

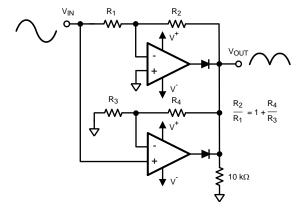


Figure 53. Precision Rectifier



REVISION HISTORY

Changes from Revision A (April 2013) to Revision B Changed layout of National Data Sheet to TI format			
•	Changed layout of National Data Sheet to TI format	. 18	



PACKAGE OPTION ADDENDUM

11-Apr-2013

PACKAGING INFORMATION

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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
SM73307MM/NOPB	ACTIVE	VSSOP	DGK	8	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	S307	Samples
SM73307MME/NOPB	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	S307	Samples
SM73307MMX/NOPB	ACTIVE	VSSOP	DGK	8	3500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	S307	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SM73307MM/NOPB	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
SM73307MME/NOPB	VSSOP	DGK	8	250	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
SM73307MMX/NOPB	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

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*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SM73307MM/NOPB	VSSOP	DGK	8	1000	210.0	185.0	35.0
SM73307MME/NOPB	VSSOP	DGK	8	250	210.0	185.0	35.0
SM73307MMX/NOPB	VSSOP	DGK	8	3500	367.0	367.0	35.0

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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